Electronic Information Disclosure Statement

INTEGRATED CIRCUITS WITH PARALLEL SELF-TESTING

Application:

Confirmation:

Applicant(s): R

Raj Kumar Jain

Docket Number:

2000P19153US

Group Art

2818

Examiner:

THONG LE

search string:

(4193125 or 4639892 or 5293386 or 5394354 or 5414653 or 5535164 or 5541872 or 5764588 or

5856940 or 5963468 or 6067265 or 6147895 or 6421797).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

lliniti	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
n	P01	4193125	1980-03-11	THE REPORT OF THE PROPERTY OF	Moriya	365	104
π	P02	4639892	1987-01-27	THE REPERT OF THE PROPERTY OF	Mizugaki et al	365	182
π	P03	5293386	1994-03-08	THE BUILDING FROM THE WORK FROM THE PROPERTY OF THE PROPERTY O	Muhmenthaler et al	371	21.1
π	P04	5394354	1995-02-28	אורעסו שונועוונוחות עווי פאינטוניות ומוונעוו	Watabe et al	365	51
元	P05	5414653	1995-05-09	HANGE CONTROL FOR THE FIRST FROM THE STATE OF THE FIRST FROM THE STATE OF THE STATE	Onishi et al	365	145
$[\pi]$	P06	5535164	1996-07-09	THE PLANT HE HELD VISITION AND THE	Adams et al	365	201
π	P07	5541872	1996-07-30		Lowrey et al	365	145
τι	P08	5764588	1998-06-09	TO THE REAL PROPERTY OF THE PROPERTY AND	Nogami et al	365	230.05

7	PO9	5856940	1999-01-05	HERET BARRIOLIST HIM IND FOLD HERTOL	Rao	365	149
72	P10	5963468	1999-10-05	MED BITH COM LOCAL BOOK BOOK BELLEVI	Rao	365	149
n	P11	6067265	2000-05-23	I I I I I I I I I I I I I I I I I I I	Mukunoki et al	365	210
TL	P12	6147895	2000-11-14	HIND BARIO OOD HOLIO BOARD	Kamp	365	145
72	P13	6421797	2002-07-16	ולנו לענו שלו השני עמה ולימו ליענו של ו בל וו וו	Kim	714	718

Remarks

(Remarks are not for responding to an office action.)

Takashima D. & Kunishima I, "High-Density Chain Ferroelectric Random Access Memory (Chain FRAM)," May 1998, IEEE Journal of Solid-State Circuits, Vol. 33, No. 5, Pg. 787-792

Signature

Examiner Name	Date
THONG LE	2./21/03
Thoyle_	9/29/03